

EAST - [10690290.wsp.1]

File View Edit Tools Window Help

☐ Drafts
☒ Pending
☒ Active
 L1: (299) semiconductor and (rocking near
 L2: (17) 1 and (reflection with "002")
 L3: (3) 6387712.URPN.
 L5: (7) ("5483568" | "6096434" | "612721
☒ Failed
☒ Saved
 (2) ("6583468").PN.
☒ Favorites
☒ Tagged (0)
☒ UDC
☒ Queue
☒ Trash

DBs: USPAT; EPO; JPO; DERWENT; IBM; TDB

Default operator: GR

☐ Plurals ☒ Highlight all hit terms initially

1 and (reflection with "002")

☒ BEST ☒ ISAR ☒ Image ☒ Text ☒ HTML

	U	I	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
1	<input type="checkbox"/>	<input type="checkbox"/>	US 6677708 B2	20040113	6	Semiconductor light-emitting element	313/498	313/506
2	<input type="checkbox"/>	<input type="checkbox"/>	US 6583468 B2	20030624	8	Semiconductor element	257/327	257/352; 257/E21.125;
3	<input type="checkbox"/>	<input type="checkbox"/>	US 6387712 B1	20020514	32	Process for preparing ferroelectric thin films	438/3	257/E21.272; 257/E29.164;
4	<input type="checkbox"/>	<input type="checkbox"/>	US 6258459 B1	20010710	26	Multilayer thin film	428/446	117/944; 365/145;
5	<input type="checkbox"/>	<input type="checkbox"/>	US 6235402 B1	20010522	12	Buffer layers on biaxially textured metal substrates	428/472	117/944; 428/469;
6	<input type="checkbox"/>	<input type="checkbox"/>	US 6198208 B1	20010306	11	Thin film piezoelectric device	310/358	428/466; 428/65.8
7	<input type="checkbox"/>	<input type="checkbox"/>	US 6121647 A	20000919	32	Film structure, electronic device, recording medium, and process of preparing	257/295	257/310; 257/E21.272;
8	<input type="checkbox"/>	<input type="checkbox"/>	US 6096434 A	20000801	32	Film structure, electronic device, recording medium, and method for forming	428/446	117/944; 257/E21.272;
9	<input type="checkbox"/>	<input type="checkbox"/>	US 6077344 A	20000620	13	Sol-gel deposition of buffer layers on biaxially textured metal substances	117/9	427/126.3; 427/126.4;
10	<input type="checkbox"/>	<input type="checkbox"/>	US 5985404 A	19991116	30	Recording medium, method of making, and information processing apparatus	428/65.3	428/141; 428/336;
11	<input type="checkbox"/>	<input type="checkbox"/>	US 5968877 A	19991019	26	High Tc YBCO superconductor deposited on biaxially textured Ni substrate	505/237	117/86; 117/947;